19-1320; Rev 1; 3/98 EVALUATION KIT MANUAL

FOLLOWS DATA SHEET

# MXXIM Low-Cost RF Up/Downconverter with LNA and PA Driver

## General Description

The MAX2410 performs the RF front-end transmit/receive function in time-division-duplex (TDD) communication systems. It operates over a wide frequency range and is optimized for RF frequencies around 1.9GHz. Applications include most popular cordless and PCS standards.

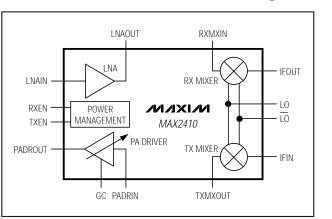
The MAX2410 contains a low-noise amplifier (LNA), a downconverter mixer, a local-oscillator (LO) buffer, an upconverter mixer, and a variable-gain power-amplifier (PA) driver in a low-cost, plastic surface-mount package. The LNA has a 2.4dB (typical) noise figure and a -10dBm input third-order intercept point (IP3). The downconverter mixer has a low 9.8dB noise figure and a 3.3dBm IP3. Image and LO filtering are implemented offchip for maximum flexibility. The PA driver has 15dB of gain, which can be reduced over a 35dB (typical) range. Power consumption is only 60mW in receive mode or 90mW in transmit mode and drops to less than 0.3µW in shutdown mode.

A similar part, the MAX2411A, features the same functionality as the MAX2410 but offers a differential bidirectional (transmit and receive) IF port. This allows the use of a single IF filter for transmit (TX) and receive (RX). For applications requiring a receive function only, consult the data sheet for the MAX2406, a low-cost downconverter with low-noise amplifier.

PWT1900 DCS1800/PCS1900 PHS/PACS



DECT **ISM-Band Transceiver** Iridium Handsets



# Functional Diagram

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### Features

**MAX2410** 

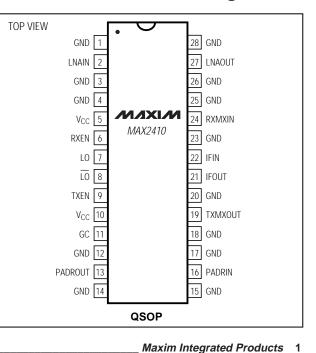
- Low-Cost Silicon Bipolar Design
- Integrated Upconvert/Downconvert Function
- Operates from Single +2.7V to +5.5V Supply
- 3.2dB Combined Receiver Noise Figure: 2.4dB (LNA) 9.8dB (Mixer)
- Flexible Power-Amplifier Driver: 18dBm Output Third-Order Intercept (OIP3) 35dB Gain Control Range
- LO Buffer for Low LO Drive Level
- Low Power Consumption: 60mW Receive 90mW Full-Power Transmit
- 0.3µW Shutdown Mode
- Flexible Power-Down Modes Compatible with MAX2510/MAX2511 IF Transceivers

### **Ordering Information**

PART	TEMP. RANGE	PIN-PACKAGE
MAX2410EEI	-40°C to +85°C	28 QSOP
MAX2410E/D	-40°C to +85°C	Dice*

\*Dice are specified at  $T_A = +25^{\circ}C$ , DC parameters only.

## Pin Configuration



## **ABSOLUTE MAXIMUM RATINGS**

V <sub>CC</sub> to GND	0.3V to +6V
LNAIN Input Power	+15dBm
LO, LO Input Power	+10dBm
PADRIN Input Power	+10dBm
RXMXIN Input Power	+10dBm
IFIN Input Power	+10dBm
RXEN, TXEN, GC Voltage	-0.3V to (V <sub>CC</sub> + 0.3V)

Continuous Power Dissipation ( $T_A = +70^{\circ}C$	2)
QSOP (derate 11mW/°C above +70°C).	909mW
Junction Temperature	+150°C
Operating Temperature Range	40°C to +85°C
Storage Temperature Range	
Lead Temperature (soldering, 10sec)	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### DC ELECTRICAL CHARACTERISTICS

 $(V_{CC} = 2.7V \text{ to } 5.5V, V_{GC} = 3.0V, RXEN = TXEN = 0.6V, IFOUT and PADROUT pulled up to V_{CC} with 50\Omega resistors, TXMXOUT pulled up to V_{CC} with 125\Omega resistor, LNAOUT pulled up to V_{CC} with 100\Omega resistor, all other RF and IF inputs open, T_A = -40°C to +85°C, unless otherwise noted. Typical values are at T_A = +25°C and V_{CC} = 3.0V.)$ 

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Supply Voltage Range		2.7		5.5	V
Digital Input Voltage High	RXEN, TXEN pins	2.0			V
Digital Input Voltage Low	RXEN, TXEN pins			0.6	V
RXEN Input Bias Current (Note 1)	RXEN = 2V		0.1	1	μA
TXEN Input Bias Current (Note 1)	TXEN = 2V		0.1	1	μΑ
GC Input Bias Current	GC = 3V, TXEN = 2V		35	46	μA
Supply Current, Receive Mode	RXEN = 2V		20	29.5	mA
Supply Current, Transmit Mode	TXEN = 2V		30	44.5	mA
Supply Current, Standby Mode	RXEN = 2V, TXEN = 2V		160	520	μΑ
Supply Current, Shutdown Mode	VCC = 3V		0.1	10	μΑ

## AC ELECTRICAL CHARACTERISTICS

 $(MAX2410 \ EV \ kit, \ V_{CC} = 3.0V, \ V_{GC} = 2.15V, \ RXEN = TXEN = low, \ f_{LO} = 1.5GHz, \ P_{LO} = -10dBm, \ f_{LNAIN} = f_{PADRIN} = f_{RXMXIN} = 1.9GHz, \ P_{LNAIN} = -32dBm, \ P_{PADRIN} = P_{RXMXIN} = -22dBm, \ f_{IFIN} = 400MHz, \ P_{IFIN} = -32dBm. \ All \ measurements \ performed \ in \ 50\Omega \ environment. \ T_A = +25^{\circ}C, \ unless \ otherwise \ noted.)$ 

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS	
LOW-NOISE AMPLIFIER (RXEN = High)						
Gain (Note 1)	$T_A = +25^{\circ}C$	14.2	16.2	17.4	dB	
Gain (Note 1)	$T_A = T_{MIN}$ to $T_{MAX}$	12.6		19.1		
Noise Figure			2.4		dB	
Input IP3	(Note 2)		-10		dBm	
Output 1dB Compression			-5		dBm	
LO to LNAIN Leakage	RXEN = high or low		-49		dBm	
<b>RECEIVE MIXER</b> (RXEN = High)	1					
Conversion Gain (Note 1)	$T_A = +25^{\circ}C$	6.6	8.3	9.8	dB	
	TA = TMIN to TMAX	5.4		10.8		
Noise Figure	Single sideband		9.8		dB	
Input IP3	(Note 3)		3.3		dBm	
Input 1dB Compression			-8		dBm	
IFOUT Frequency	(Notes 1, 4)			450	MHz	
Minimum LO Drive Level	(Note 5)		-17		dBm	

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## AC ELECTRICAL CHARACTERISTICS (continued)

(MAX2410 EV kit, V<sub>CC</sub> = 3.0V, V<sub>GC</sub> = 2.15V, RXEN = TXEN = Iow,  $f_{LO}$  = 1.5GHz,  $P_{LO}$  = -10dBm,  $f_{LNAIN}$  =  $f_{PADRIN}$  =  $f_{RXMXIN}$  = 1.9GHz,  $P_{LNAIN}$  = -32dBm,  $P_{PADRIN}$  =  $P_{RXMXIN}$  = -22dBm,  $f_{IFIN}$  = 400MHz,  $P_{IFIN}$  = -32dBm. All measurements performed in 50 $\Omega$  environment. TA = +25°C, unless otherwise noted.)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
<b>TRANSMIT MIXER</b> (TXEN = high)					
Conversion Cain (Note 1)	$T_{A} = +25^{\circ}C$	8.6	10	11.1	- dB
Conversion Gain (Note 1)	$T_A = T_{MIN}$ to $T_{MAX}$	7.3		11.8	
Output IP3	(Note 6)		-0.3		dBm
Output 1dB Compression Point			-11.4		dBm
LO Leakage			-52		dBm
Noise Figure	Single sideband		8.2		dB
IFIN Frequency	(Notes 1, 4)			450	MHz
	$f_{OUT} = 2LO-2IF = 2.2GHz$		-44		dBc
Intermod Spurious Response (Note 7)	fout = 2LO-3IF = 1.8GHz		-74		dBc
	$f_{OUT} = 3LO-6IF = 2.1GHz$		-90		dBc
POWER AMPLIFIER DRIVER (TXEN	l = high)	· · ·			
Gain (Note 1)	$T_{A} = +25^{\circ}C$	13	15	16.4	dB
Gain (Note 1)	$T_A = T_{MIN}$ to $T_{MAX}$	12.3		17	
Output IP3	(Note 3)		18		dBm
Output 1dB Compression Point			6.3		dBm
Gain-Control Range			35		dB
Gain-Control Sensitivity	(Note 8)		12		dB/V
LOCAL OSCILLATOR INPUTS (RXE	N = TXEN = high)	·			
Input Relative VSWR Normalized to	Receive (TXEN = Low)		1.10		
Standby-Mode Impedance	Transmit (RXEN = Low)		1.02		1
<b>POWER MANAGEMENT</b> (RXEN = T	XEN = low)	1			
Receiver Turn-On Time	(Notes 1, 9)		0.5	2.5	μs
Transmitter Turn-On Time	(Notes 1, 10)		0.3	2.5	μs

Note 1: Guaranteed by design and characterization.

Note 2: Two tones at 1.9GHz and 1.901GHz at -32dBm per tone

**Note 3:** Two tones at 1.9GHz and 1.901GHz at -22dBm per tone

**Note 4:** Mixer operation guaranteed to this frequency. For optimum gain, adjust output match. See the *Typical Operating Characteristics* for graphs of IFIN and IFOUT Impedance vs. IF Frequency.

Note 5: At this LO drive level the mixer conversion gain is typically 1dB lower than with -10dBm LO drive.

**Note 6:** Two tones at 400MHz and 401MHz at -32dBm per tone.

Note 7: Transmit mixer output at -17dBm.

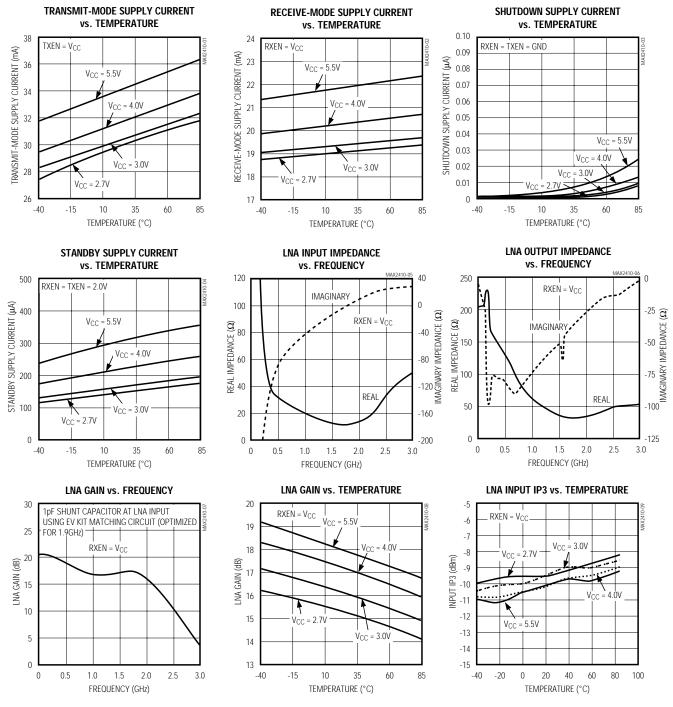
**Note 8:** Calculated from measurements taken at  $V_{GC} = 1.0V$  and  $V_{GC} = 1.5V$ .

**Note 9:** Time from RXEN = low to RXEN = high transition until the combined receive gain is within 1dB of its final value. Measured with 47pF blocking capacitors on LNAIN and LNAOUT.

**Note 10:** Time from TXEN = low to TXEN = high transition until the combined transmit gain is within 1dB of its final value. Measured with 47pF blocking capacitors on PADRIN and PADROUT.

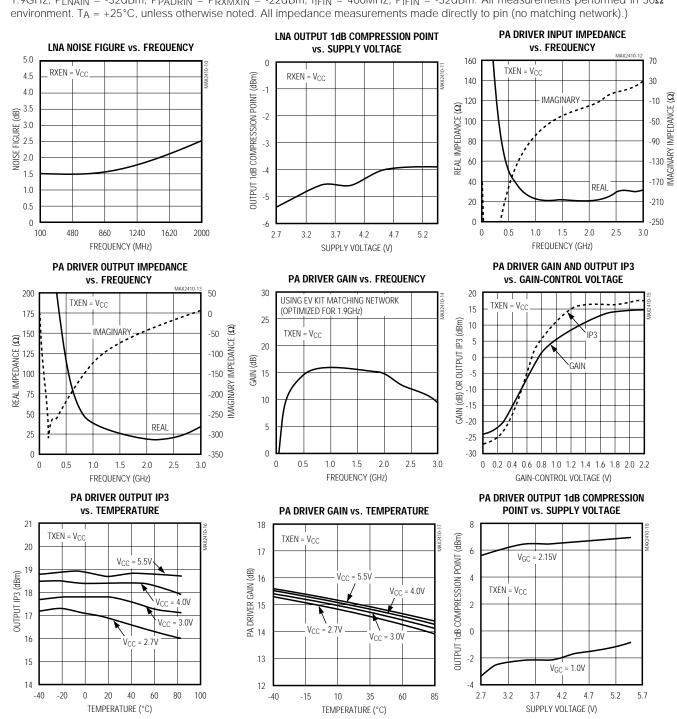
# Typical Operating Characteristics

(MAX2410 EV kit, V<sub>CC</sub> = 3.0V, V<sub>GC</sub> = 2.15V, RXEN = TXEN = Iow,  $f_{LO}$  = 1.5GHz,  $P_{LO}$  = -10dBm,  $f_{LNAIN}$  =  $f_{PADRIN}$  =  $f_{RXMXIN}$  = 1.9GHz,  $P_{LNAIN}$  = -32dBm,  $P_{PADRIN}$  =  $P_{RXMXIN}$  = -22dBm,  $f_{IFIN}$  = 400MHz,  $P_{IFIN}$  = -32dBm. All measurements performed in 50 $\Omega$  environment. T<sub>A</sub> = +25°C, unless otherwise noted. All impedance measurements made directly to pin (no matching network).)



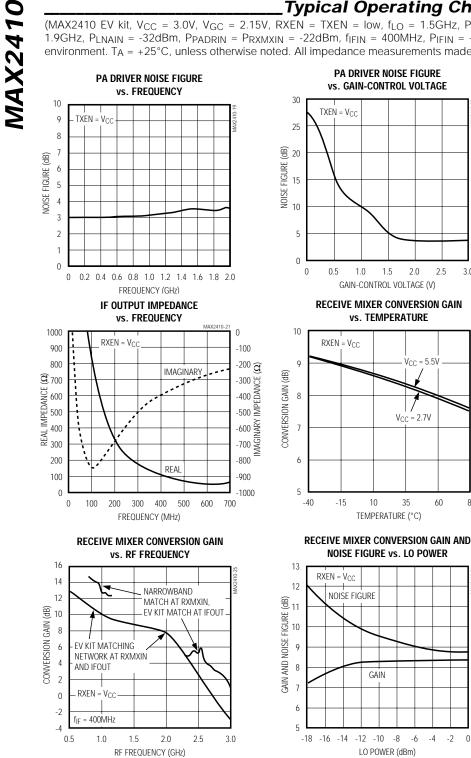


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## Typical Operating Characteristics (continued)

 $(MAX2410 \text{ EV kit}, \text{ V}_{CC} = 3.0\text{V}, \text{ V}_{GC} = 2.15\text{V}, \text{ RXEN} = \text{TXEN} = \text{Iow}, \text{ } \text{f}_{LO} = 1.5\text{GHz}, \text{P}_{LO} = -10\text{dBm}, \text{ } \text{f}_{LNAIN} = \text{f}_{PADRIN} = \text{f}_{RXMXIN} = 1.9\text{GHz}, \text{P}_{LNAIN} = -32\text{dBm}, \text{P}_{PADRIN} = \text{P}_{RXMXIN} = -22\text{dBm}, \text{f}_{IFIN} = 400\text{MHz}, \text{P}_{IFIN} = -32\text{dBm}. \text{ All measurements performed in 50} \Omega \text{ environment}. \text{ T}_{A} = +25^{\circ}\text{C}, \text{ unless otherwise noted}. \text{ All impedance measurements made directly to pin (no matching network).}$ 



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**Typical Operating Characteristics (continued)** 

(MAX2410 EV kit, V<sub>CC</sub> = 3.0V, V<sub>GC</sub> = 2.15V, RXEN = TXEN = Iow, f<sub>LO</sub> = 1.5GHz, P<sub>LO</sub> = -10dBm, f<sub>LNAIN</sub> = f<sub>PADRIN</sub> = f<sub>RXMXIN</sub> = 1.9GHz, PLNAIN = -32dBm, PPADRIN = PRXMXIN = -22dBm, fIFIN = 400MHz, PIFIN = -32dBm. All measurements performed in 50Ω environment.  $T_A = +25$  °C, unless otherwise noted. All impedance measurements made directly to pin (no matching network).)

> 2.0 2.5

 $V_{CC} = 5.5V$ 

 $V_{CC} = 2.7V$ 

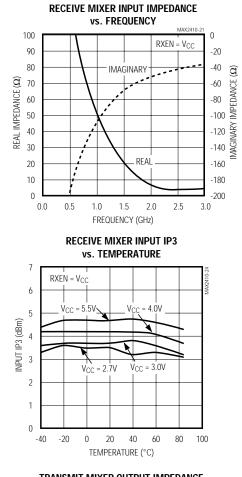
35

-8 -6 -4 -2 0

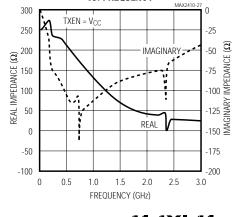
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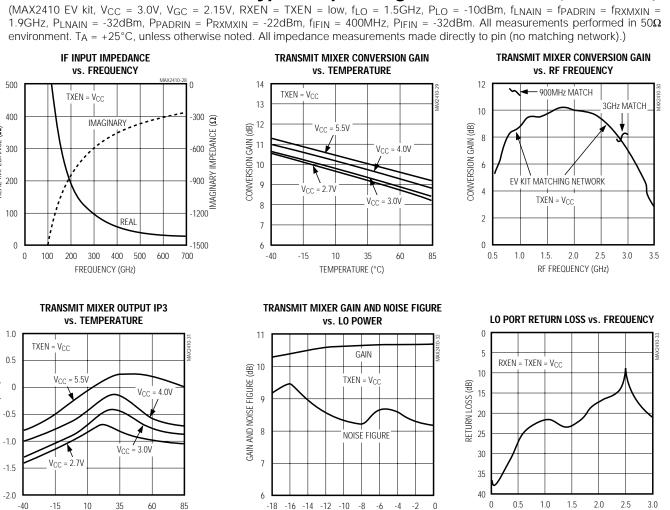
3.0



TRANSMIT MIXER OUTPUT IMPEDANCE vs. FREQUENCY



M /X / M



LO POWER (dBm)

### Typical Operating Characteristics (continued)

### /M/IXI/M

TEMPERATURE (°C)

G

REAL IMPEDANCE

OUTPUT IP3 (dBm)

\_ 7

FREQUENCY (GHz)

\_\_Pin Description

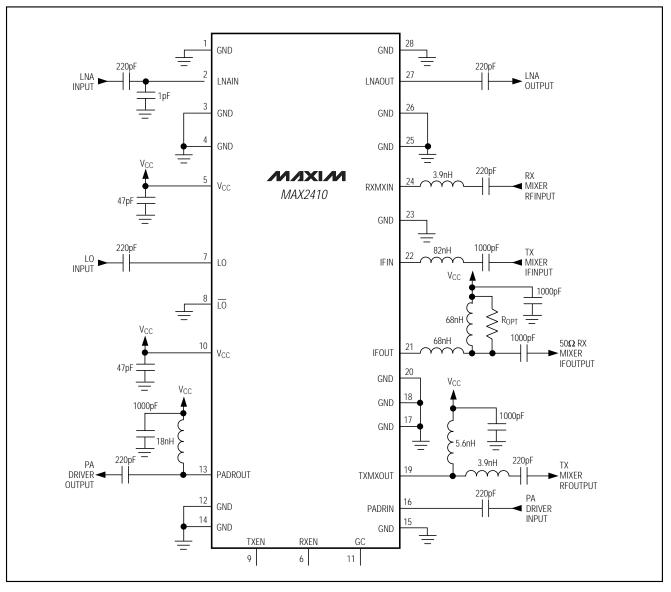
PIN	NAME	FUNCTION	
1, 3, 4, 12, 14, 18, 20, 23, 28	GND	Ground. Connect to PC board ground plane with minimal inductance.	
2	LNAIN	F Input to the LNA. AC couple to this pin. At 1.9GHz, LNAIN can be easily matched to $50\Omega$ with one sternal shunt 1pF capacitor.	
5, 10	V <sub>CC</sub>	Supply Voltage (2.7V to 5.5V). Bypass $V_{CC}$ to GND at each pin with a 47pF capacitor as close to each pin as possible.	
6	RXEN	Logic-Level Enable for Receiver Circuitry. A logic high turns on the receiver. When TXEN and RXEN are both at a logic high, the part is placed in standby mode, with a supply current of 160µA (typical). If TXEN and RXEN are both at a logic low, the part is set to shutdown mode, with a supply current of 0.1µA (typical).	
7	LO	50Ω Local-Oscillator (LO) Input Port. AC couple to this pin.	
8	LO	50 $\Omega$ Inverting Local-Oscillator Input Port. For single-ended operation connect $\overline{LO}$ directly to GND. If a differential LO signal is available, AC couple the inverted LO signal to this pin.	
9	TXEN	Logic-Level Enable for Transmitter Circuitry. A logic high turns on the transmitter. When TXEN and RXEN are both at a logic high, the part is placed in standby mode, with 160µA (typical) supply current. If TXEN and RXEN are both at a logic low, the part is set to shutdown mode, with 0.1µA (typical) supply current.	
11	GC	Gain-Control Input for Power-Amplifier Driver. By applying an analog control voltage between 0V and 2.15V, the gain of the PA driver can be adjusted over a 35dB range. Connect to $V_{CC}$ for maximum gain.	
13	PADROUT	Power-Amplifier Driver Output. AC couple to this pin. Use external shunt inductor to $V_{CC}$ to match this pin to 50 $\Omega$ . This also provides DC bias. See the <i>Typical Operating Characteristics</i> for a plot of PADROUT Impedance vs. Frequency.	
15, 17	GND	Power-Amplifier Driver Input Ground. Connect to PC board ground plane with minimal inductance.	
16	PADRIN	RF Input to Variable-Gain Power-Amplifier Driver. AC couple to this pin. Internally matched to $50\Omega$ . This input typically provides a 2:1 VSWR at 1.9GHz. See the <i>Typical Operating Characteristics</i> for a plot of PADRIN Impedance vs. Frequency.	
19	TXMXOUT	RF Output of Transmit Mixer (Upconverter). AC couple to this pin. Use an external shunt inductor to $V_{CC}$ as part of a matching network to $50\Omega$ . This also provides DC bias. See the <i>Typical Operating Characteristics</i> for a plot of TXMXOUT Impedance vs. Frequency.	
21	IFOUT	IF Output of Receive Mixer (Downconverter). AC couple to this pin. This output is an open collector and should be pulled up to V <sub>CC</sub> with an inductor. This inductor can be part of the matching network to the desired IF impedance. Alternatively, a resistor can be placed in parallel to this inductor to set a terminating impedance. See the <i>Typical Operating Circuit</i> for more information.	
22	IFIN	IF Input of Transmit Mixer (Upconverter). AC couple to this pin. IFIN presents a high input impedance and typically requires a matching network. See the <i>Typical Operating Characteristics</i> for a plot of IFIN Impedance vs. Frequency.	
24	RXMXIN	RF Input to Receive Mixer (Downconverter). AC couple to this pin. This input typically requires a matching network for connecting to an external filter. See the <i>Typical Operating Characteristics</i> for a plot of RXMXIN Impedance vs. Frequency.	
25	GND	Receive Mixer Input Ground. Connect to PC board ground plane with minimal inductance.	
26	GND	LNA Output Ground. Connect to PC board ground plane with minimal inductance.	
27	LNAOUT	LNA Output. AC couple to this pin. This output typically provides a VSWR of better than 2:1 at frequencies from 1.7GHz to 3GHz with no external matching components. At other frequencies, a matching network may be required to match this pin to an external filter. Consult the <i>Typical Operating Characteristics</i> for a plot of LNA Output Impedance vs. Frequency.	



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# \_Typical Operating Circuit

**MAX2410** 



## Detailed Description

The MAX2410 consists of five major components: a transmit mixer, a variable-gain power-amplifier (PA) driver, a low-noise amplifier (LNA), a receive mixer, and power-management section.

The following sections describe each block in the MAX2410 *Functional Diagram*.

#### Low-Noise Amplifier (LNA)

The LNA is a wideband, single-ended cascode amplifier that can be used over a wide range of frequencies (refer to the LNA Gain vs. Frequency graph in the *Typical Operating Characteristics*). Its port impedances are optimized for operation around 1.9GHz, requiring only a 1pF shunt capacitor at the LNA input for a VSWR of better than 2:1 and a noise figure of 2.4dB. As with every LNA, the input match can be traded off for better noise figure.

#### PA Driver

The PA driver typically has 15dB of gain, which is adjustable over a 35dB range via the GC pin. At full gain, the PA driver has a noise figure of 3.5dB at 1.9GHz.

For input and output matching information, refer to the *Typical Operating Characteristics* for plots of PA Driver Input and Output Impedance vs. Frequency.

#### **Receive Mixer**

The receive mixer is a wideband, double-balanced design with excellent noise figure and linearity. The inputs to the mixer are the RF signal at the RXMXIN pin and the LO inputs at LO and  $\overline{\text{LO}}$ . The downconverted output signal appears at the IFOUT port. The conversion gain of the receive mixer is typically 8.3dB with a noise figure of 9.8dB.

#### RF Input

The RXMXIN input is typically connected to the LNA output through an off-chip filter. This input is externally matched to  $50\Omega$ . See the *Typical Operating Circuit* for an example matching network and the RXMXIN Impedance vs. Frequency graph in the *Typical Operating Characteristics*.

#### Local-Oscillator Inputs

The LO and  $\overline{\text{LO}}$  pins are internally terminated with 50 $\Omega$  on-chip resistors. AC couple the LO signal to these pins. If a single-ended LO source is used, connect  $\overline{\text{LO}}$  directly to ground.

#### IF Output Port

The MAX2410's receive mixer output appears at the IFOUT pin, an open-collector output that requires an external pull-up inductor to  $V_{CC}$ . This inductor can be part of a matching network to the desired IF impedance. Alternatively, a resistor can be placed in parallel with the pull-up inductor to set a terminating impedance.

The MAX2411A, a similar part to the MAX2410, has the same functionality as the MAX2410 but offers a differential, bidirectional (transmit and receive) IF port. This allows sharing of TX and RX IF filters, which for some applications provides a lower cost, smaller solution.

#### Transmit Mixer

The transmit mixer takes an IF signal at the IFIN pin and upconverts it to an RF frequency at the TXMXOUT pin. The conversion gain is typically 10dB and the output 1dB compression point is typically -11.4dBm at 1.9GHz.

#### RF Output

The transmit mixer output appears on the TXMXOUT pin. It is an open-collector output that requires an external pull-up inductor to V<sub>CC</sub> for DC biasing, which can be part of an impedance-matching network. Consult the *Typical Operating Characteristics* for a plot of TXMXOUT Impedance vs Frequency.

#### IF Input

The IFIN pin is a self-biasing input that must be ACcoupled to the IF source. Refer to the *Typical Operating Characteristics* for plots of Input and Output Impedance vs. Frequency.

#### Local-Oscillator Inputs

The LO and  $\overline{\text{LO}}$  pins are terminated with 50 $\Omega$  on-chip resistors. AC couple the LO signal to these pins. If a single-ended LO source is used, connect  $\overline{\text{LO}}$  directly to GND.

#### Advanced System Power Management

RXEN and TXEN are the two separate power-control inputs for the receiver and the transmitter. If both inputs are at logic 0, the part enters shutdown mode and the supply current drops below 1 $\mu$ A. When one input is brought to a logic 1, the corresponding function is enabled. If RXEN and TXEN are both set to logic 1, the part enters standby mode as described in the *Standby Mode* section. Table 1 summarizes these operating modes.

Power-down is guaranteed with a control voltage at or below 0.6V. The power-down function is designed to reduce the total power consumption to less than  $1\mu$ A in less than 2.5 $\mu$ s. Complete power-up will happen in the same amount of time.

# Table 1. Advanced System Power-Management Functions

RXEN	TXEN	FUNCTION	
0	0	Shutdown	
0	1 Transmit		
1	0	Receive	
1	1	Standby Mode	

#### Standby Mode

When the TXEN and RXEN pins are both set to logic 1, all functions are disabled and the supply current drops to  $160\mu A$  (typical). This mode is called standby, and it corresponds to a standby mode on the compatible IF transceiver chips MAX2510 and MAX2511.

#### \_Applications Information

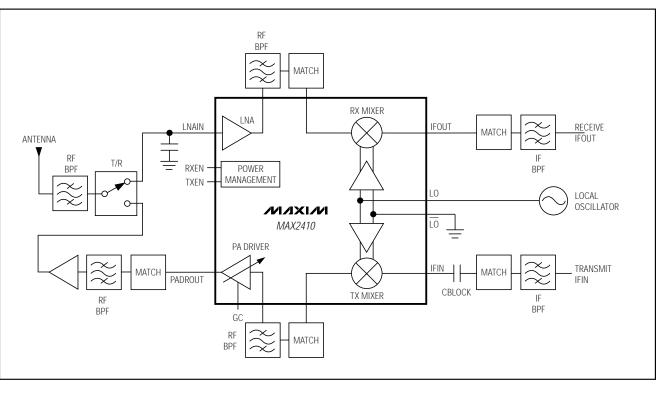
#### **Extended Frequency Range**

The MAX2410 has been characterized at 1.9GHz for use in PCS-band applications; however, it operates over a much wider frequency range. The LNA gain and noise figure, as well as mixer conversion gain, are plotted over a wide frequency range in the *Typical Operating Characteristics*. When operating the device at RF frequencies other than those specified in the *AC Electrical Characteristics* table, it may be necessary to design or alter the matching networks on the RF ports. If the IF frequency is different than that specified in the *AC Electrical Characteristics* table, the IFIN and IFOUT matching networks must be altered. The *Typical Operating Characteristics* provide Port Impedance Data vs. Frequency on all RF and IF pins for use in designing matching networks. The LO port (LO and  $\overline{\text{LO}}$ ) is internally terminated with 50 $\Omega$  resistors and provides a VSWR of approximately 1.2:1 to 2GHz and 2:1 up to 3GHz.

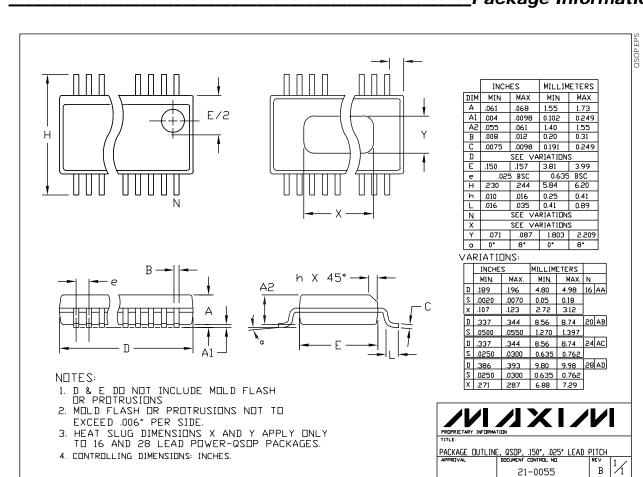
#### Layout Issues

A properly designed PC board is an essential part of any RF/microwave circuit. Be sure to use controlled impedance lines on all high-frequency inputs and outputs. Use low-inductance connections to ground on all GND pins, and place decoupling capacitors close to all Vcc connections.

For the power supplies, a star topology works well. In a star topology, each V<sub>CC</sub> node in the circuit has its own path to the central V<sub>CC</sub>, and its own decoupling capacitor which provides a low impedance at the RF frequency of interest. The central V<sub>CC</sub> node has a large decoupling capacitor as well, to provide good isolation between the different sections of the MAX2410. The MAX2410 EV kit layout can be used as a guide to integrating the MAX2410 into your design.



## Typical Application Block Diagram



## Package Information

# **X-ON Electronics**

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Click to view similar products for Up-Down Converters category:

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HMC7586-SX HMC7587 HMC8119-SX HMC7587-SX HMC6147ALC5ATR MDS-158-PIN LA8153QA-WH HMC7912LP5ETR HMC377QS16GETR MY87C CSM2-10 CHR3762-QDG AD6620ASZ-REEL ADF5904ACPZ ADF5904WCCPZ AD6623ASZ AD6633BBCZ AD6634BBCZ AD9957BSVZ AD9957BSVZ-REEL ADMV1009AEZ ADMV1010AEZ ADMV1011AEZ ADMV1012AEZ ADRF6658BCPZ HMC951ALP4E HMC571 HMC6146BLC5A HMC571LC5 HMC572LC5 HMC925LC5 HMC6787ALC5A HMC6787ALC5ATR HMC682LP6CE HMC571LC5TR HMC7911LP5E HMC7912LP5E HMC908ALC5 HMC951BLP4ETR HMC967LP4E HMC977LP4E AD6634BBC HMC6505ALC5 MAUC-011003-TR0500 MAX9996ETP+T MAX19996AETP+ MAX19996ETP+ MAX2039ETP+ MAX2410EEI+ MAX2411AEEI+